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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Active
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	80MHz
Connectivity	CANbus, EBI/EMI, I <sup>2</sup> C, IrDA, LINbus, MMC/SD, QSPI, SAI, SPI, SWPMI, UART/USART, USB OTG
Peripherals	Brown-out Detect/Reset, DMA, LCD, PWM, WDT
Number of I/O	114
Program Memory Size	1MB (1M x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	128K x 8
Voltage - Supply (Vcc/Vdd)	1.71V ~ 3.6V
Data Converters	A/D 24x12b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	144-LQFP
Supplier Device Package	144-LQFP (20x20)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/stmicroelectronics/stm32l476zgt6u">https://www.e-xfl.com/product-detail/stmicroelectronics/stm32l476zgt6u</a>

## 2 Description

The STM32L476xx devices are the ultra-low-power microcontrollers based on the high-performance ARM® Cortex®-M4 32-bit RISC core operating at a frequency of up to 80 MHz. The Cortex-M4 core features a Floating point unit (FPU) single precision which supports all ARM single-precision data-processing instructions and data types. It also implements a full set of DSP instructions and a memory protection unit (MPU) which enhances application security.

The STM32L476xx devices embed high-speed memories (Flash memory up to 1 Mbyte, up to 128 Kbyte of SRAM), a flexible external memory controller (FSMC) for static memories (for devices with packages of 100 pins and more), a Quad SPI flash memories interface (available on all packages) and an extensive range of enhanced I/Os and peripherals connected to two APB buses, two AHB buses and a 32-bit multi-AHB bus matrix.

The STM32L476xx devices embed several protection mechanisms for embedded Flash memory and SRAM: readout protection, write protection, proprietary code readout protection and Firewall.

The devices offer up to three fast 12-bit ADCs (5 Msps), two comparators, two operational amplifiers, two DAC channels, an internal voltage reference buffer, a low-power RTC, two general-purpose 32-bit timer, two 16-bit PWM timers dedicated to motor control, seven general-purpose 16-bit timers, and two 16-bit low-power timers. The devices support four digital filters for external sigma delta modulators (DFSDM).

In addition, up to 24 capacitive sensing channels are available. The devices also embed an integrated LCD driver 8x40 or 4x44, with internal step-up converter.

They also feature standard and advanced communication interfaces.

- Three I2Cs
- Three SPIs
- Three USARTs, two UARTs and one Low-Power UART.
- Two SAs (Serial Audio Interfaces)
- One SDMMC
- One CAN
- One USB OTG full-speed
- One SWPMI (Single Wire Protocol Master Interface)

The STM32L476xx operates in the -40 to +85 °C (+105 °C junction), -40 to +105 °C (+125 °C junction) and -40 to +125 °C (+130 °C junction) temperature ranges from a 1.71 to 3.6 V power supply. A comprehensive set of power-saving modes allows the design of low-power applications.

Some independent power supplies are supported: analog independent supply input for ADC, DAC, OPAMPs and comparators, 3.3 V dedicated supply input for USB and up to 14 I/Os can be supplied independently down to 1.08V. A VBAT input allows to backup the RTC and backup registers.

The STM32L476xx family offers six packages from 64-pin to 144-pin packages.

### 3.21 Liquid crystal display controller (LCD)

The LCD drives up to 8 common terminals and 44 segment terminals to drive up to 320 pixels.

- Internal step-up converter to guarantee functionality and contrast control irrespective of  $V_{DD}$ . This converter can be deactivated, in which case the VLCD pin is used to provide the voltage to the LCD
- Supports static, 1/2, 1/3, 1/4 and 1/8 duty
- Supports static, 1/2, 1/3 and 1/4 bias
- Phase inversion to reduce power consumption and EMI
- Integrated voltage output buffers for higher LCD driving capability
- Up to 8 pixels can be programmed to blink
- Unneeded segments and common pins can be used as general I/O pins
- LCD RAM can be updated at any time owing to a double-buffer
- The LCD controller can operate in Stop mode

### 3.22 Digital filter for Sigma-Delta Modulators (DFSDM)

The device embeds one DFSDM with 4 digital filters modules and 8 external input serial channels (transceivers) or alternately 8 internal parallel inputs support.

The DFSDM peripheral is dedicated to interface the external  $\Sigma\Delta$  modulators to microcontroller and then to perform digital filtering of the received data streams (which represent analog value on  $\Sigma\Delta$  modulators inputs). DFSDM can also interface PDM (Pulse Density Modulation) microphones and perform PDM to PCM conversion and filtering in hardware. DFSDM features optional parallel data stream inputs from microcontrollers memory (through DMA/CPU transfers into DFSDM).

DFSDM transceivers support several serial interface formats (to support various  $\Sigma\Delta$  modulators). DFSDM digital filter modules perform digital processing according user selected filter parameters with up to 24-bit final ADC resolution.

The major features are:

- Combined Rx and Tx FIFO size of 1.25 KB with dynamic FIFO sizing
- Supports the session request protocol (SRP) and host negotiation protocol (HNP)
- 1 bidirectional control endpoint + 5 IN endpoints + 5 OUT endpoints
- 8 host channels with periodic OUT support
- HNP/SNP/IP inside (no need for any external resistor)
- Software configurable to OTG 1.3 and OTG 2.0 modes of operation
- OTG 2.0 Supports ADP (Attach detection Protocol)
- USB 2.0 LPM (Link Power Management) support
- Battery Charging Specification Revision 1.2 support
- Internal FS OTG PHY support

For OTG/Host modes, a power switch is needed in case bus-powered devices are connected.

### 3.35 Flexible static memory controller (FSMC)

The Flexible static memory controller (FSMC) includes two memory controllers:

- The NOR/PSRAM memory controller
- The NAND/memory controller

This memory controller is also named Flexible memory controller (FMC).

The main features of the FMC controller are the following:

- Interface with static-memory mapped devices including:
  - Static random access memory (SRAM)
  - NOR Flash memory/OneNAND Flash memory
  - PSRAM (4 memory banks)
  - NAND Flash memory with ECC hardware to check up to 8 Kbyte of data
- 8-,16- bit data bus width
- Independent Chip Select control for each memory bank
- Independent configuration for each memory bank
- Write FIFO
- The Maximum FMC\_CLK frequency for synchronous accesses is HCLK/2.

#### LCD parallel interface

The FMC can be configured to interface seamlessly with most graphic LCD controllers. It supports the Intel 8080 and Motorola 6800 modes, and is flexible enough to adapt to specific LCD interfaces. This LCD parallel interface capability makes it easy to build cost effective graphic applications using LCD modules with embedded controllers or high performance solutions using external controllers with dedicated acceleration.

Table 15. STM32L476xxSTM32L476xx pin definitions (continued)

Pin Number						Pin name (function after reset)	Pin type	I/O structure	Notes	Pin functions	
LQFP64	WLCSP72	WLCSP81	LQFP100	UFPGA132	LQFP144					Alternate functions	Additional functions
-	-	-	82	B9	115	PD1	I/O	FT	-	SPI2_SCK, DFSDM_CKIN7, CAN1_TX, FMC_D3, EVENTOUT	-
54	A3	A3	83	C8	116	PD2	I/O	FT_I	-	TIM3_ETR, USART3_RTS_DE, UART5_RX, TSC_SYNC, LCD_COM7/LCD_SEG31/ LCD_SEG43, SDMMC1_CMD, EVENTOUT	-
-	-	-	84	B8	117	PD3	I/O	FT	-	SPI2_MISO, DFSDM_DATIN0, USART2_CTS, FMC_CLK, EVENTOUT	-
-	-	E5	85	B7	118	PD4	I/O	FT	-	SPI2_MOSI, DFSDM_CKIN0, USART2_RTS_DE, FMC_NOE, EVENTOUT	-
-	-	D4	86	A6	119	PD5	I/O	FT	-	USART2_TX, FMC_NWE, EVENTOUT	-
-	-	-	-	-	120	VSS	S	-	-	-	-
-	-	E4	-	-	121	VDD	S	-	-	-	-
-	-	D5	87	B6	122	PD6	I/O	FT	-	DFSDM_DATIN1, USART2_RX, FMC_NWAIT, SAI1_SD_A, EVENTOUT	-
-	-	D6	88	A5	123	PD7	I/O	FT	-	DFSDM_CKIN1, USART2_CK, FMC_NE1, EVENTOUT	-
-	A4	A4	-	D9	124	PG9	I/O	FT_s	-	SPI3_SCK, USART1_TX, FMC_NCE3/FMC_NE2, SAI2_SCK_A, TIM15_CH1N, EVENTOUT	-
-	B4	B4	-	D8	125	PG10	I/O	FT_s	-	LPTIM1_IN1, SPI3_MISO, USART1_RX, FMC_NE3, SAI2_FS_A, TIM15_CH1, EVENTOUT	-
-	C4	C4	-	G3	126	PG11	I/O	FT_s	-	LPTIM1_IN2, SPI3_MOSI, USART1_CTS, SAI2_MCLK_A, TIM15_CH2, EVENTOUT	-

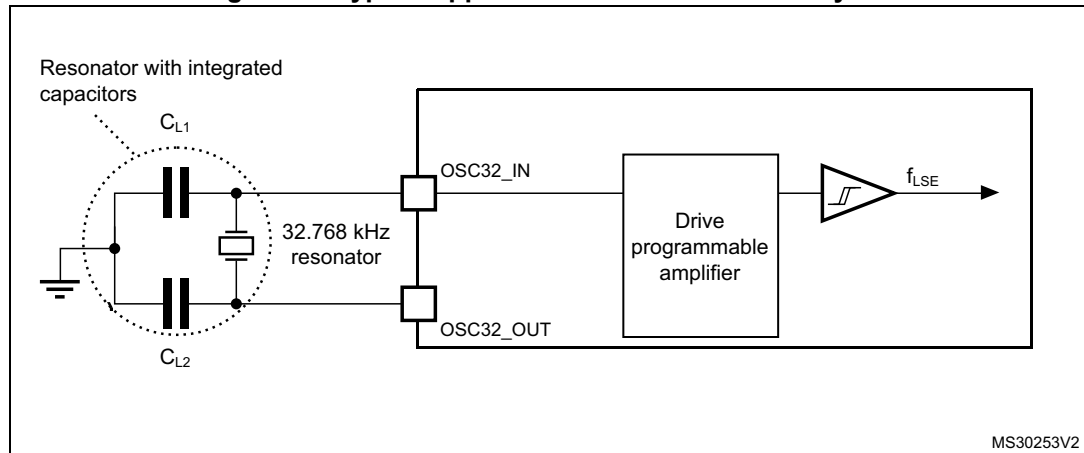
Table 17. Alternate function AF8 to AF15 (for AF0 to AF7 see [Table 16](#)) (continued)

Port		AF8	AF9	AF10	AF11	AF12	AF13	AF14	AF15
		UART4, UART5, LPUART1	CAN1, TSC	OTG_FS, QUADSPI	LCD	SDMMC1, COMP1, COMP2, FMC, SWPMI1	SAI1, SAI2	TIM2, TIM15, TIM16, TIM17, LPTIM2	EVENTOUT
Port G	PG0	-	TSC_G8_IO3	-	-	FMC_A10	-	-	EVENTOUT
	PG1	-	TSC_G8_IO4	-	-	FMC_A11	-	-	EVENTOUT
	PG2	-	-	-	-	FMC_A12	SAI2_SCK_B	-	EVENTOUT
	PG3	-	-	-	-	FMC_A13	SAI2_FS_B	-	EVENTOUT
	PG4	-	-	-	-	FMC_A14	SAI2_MCLK_B	-	EVENTOUT
	PG5	LPUART1_CTS	-	-	-	FMC_A15	SAI2_SD_B	-	EVENTOUT
	PG6	LPUART1_RTS_DE	-	-	-	-	-	-	EVENTOUT
	PG7	LPUART1_TX	-	-	-	FMC_INT3	-	-	EVENTOUT
	PG8	LPUART1_RX	-	-	-	-	-	-	EVENTOUT
	PG9	-	-	-	-	FMC_NCE3/ FMC_NE2	SAI2_SCK_A	TIM15_CH1N	EVENTOUT
	PG10	-	-	-	-	FMC_NE3	SAI2_FS_A	TIM15_CH1	EVENTOUT
	PG11	-	-	-	-	-	SAI2_MCLK_A	TIM15_CH2	EVENTOUT
	PG12	-	-	-	-	FMC_NE4	SAI2_SD_A	-	EVENTOUT
	PG13	-	-	-	-	FMC_A24	-	-	EVENTOUT
	PG14	-	-	-	-	FMC_A25	-	-	EVENTOUT
	PG15	-	-	-	-	-	-	-	EVENTOUT

1. Guaranteed by design.
2. Refer to the note and caution paragraphs below the table, and to the application note AN2867 "Oscillator design guide for ST microcontrollers".
3.  $t_{SU(LSE)}$  is the startup time measured from the moment it is enabled (by software) to a stabilized 32.768 kHz oscillation is reached. This value is measured for a standard crystal and it can vary significantly with the crystal manufacturer

**Note:** For information on selecting the crystal, refer to the application note AN2867 "Oscillator design guide for ST microcontrollers" available from the ST website [www.st.com](http://www.st.com).

**Figure 19. Typical application with a 32.768 kHz crystal**



**Note:** An external resistor is not required between OSC32\_IN and OSC32\_OUT and it is forbidden to add one.

### 6.3.14 I/O port characteristics

#### General input/output characteristics

Unless otherwise specified, the parameters given in [Table 58](#) are derived from tests performed under the conditions summarized in [Table 22: General operating conditions](#). All I/Os are designed as CMOS- and TTL-compliant (except BOOT0).

**Table 58. I/O static characteristics**

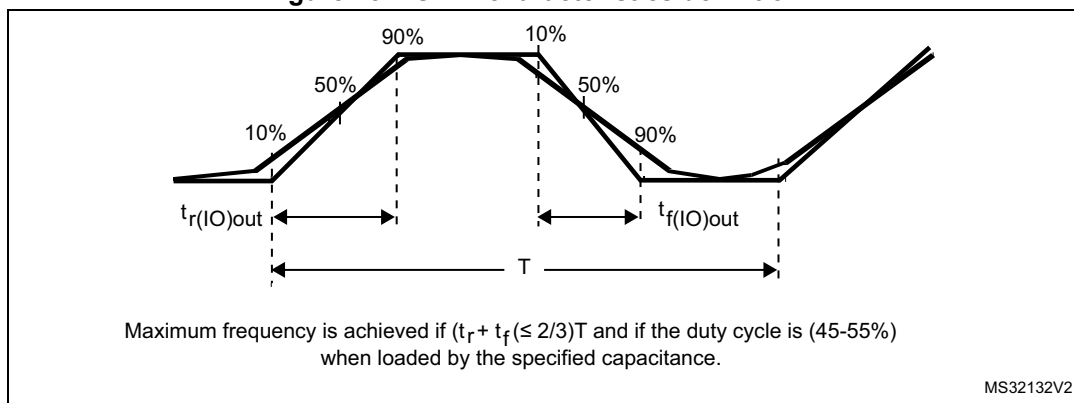
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{IL}^{(1)}$	I/O input low level voltage except BOOT0	$1.62\text{ V} < V_{DDIOx} < 3.6\text{ V}$	-	-	$0.3 \times V_{DDIOx}^{(2)}$	V
	I/O input low level voltage except BOOT0	$1.62\text{ V} < V_{DDIOx} < 3.6\text{ V}$	-	-	$0.39 \times V_{DDIOx} - 0.06^{(3)}$	
	I/O input low level voltage except BOOT0	$1.08\text{ V} < V_{DDIOx} < 1.62\text{ V}$	-	-	$0.43 \times V_{DDIOx} - 0.1^{(3)}$	
	BOOT0 I/O input low level voltage	$1.62\text{ V} < V_{DDIOx} < 3.6\text{ V}$	-	-	$0.17 \times V_{DDIOx}^{(3)}$	
$V_{IH}^{(1)}$	I/O input high level voltage except BOOT0	$1.62\text{ V} < V_{DDIOx} < 3.6\text{ V}$	$0.7 \times V_{DDIOx}^{(2)}$	-	-	V
	I/O input high level voltage except BOOT0	$1.62\text{ V} < V_{DDIOx} < 3.6\text{ V}$	$0.49 \times V_{DDIOx} + 0.26^{(3)}$	-	-	
	I/O input high level voltage except BOOT0	$1.08\text{ V} < V_{DDIOx} < 1.62\text{ V}$	$0.61 \times V_{DDIOx} + 0.05^{(3)}$	-	-	
	BOOT0 I/O input high level voltage	$1.62\text{ V} < V_{DDIOx} < 3.6\text{ V}$	$0.77 \times V_{DDIOx}^{(3)}$	-	-	
$V_{hys}^{(3)}$	TT_xx, FT_xxx and NRST I/O input hysteresis	$1.62\text{ V} < V_{DDIOx} < 3.6\text{ V}$	-	200	-	mV
	FT_sx	$1.08\text{ V} < V_{DDIOx} < 1.62\text{ V}$	-	150	-	
	BOOT0 I/O input hysteresis	$1.62\text{ V} < V_{DDIOx} < 3.6\text{ V}$	-	200	-	



Table 58. I/O static characteristics (continued)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$I_{lkg}$	FT_xx input leakage current <sup>(3)</sup>	$V_{IN} \leq \text{Max}(V_{DDXXX})^{(4)}$	-	-	$\pm 100$	nA
		$\text{Max}(V_{DDXXX}) \leq V_{IN} \leq \text{Max}(V_{DDXXX}) + 1 \text{ V}^{(4)(5)}$	-	-	$650^{(3)(6)}$	
		$\text{Max}(V_{DDXXX}) + 1 \text{ V} < V_{IN} \leq 5.5 \text{ V}^{(3)(5)}$	-	-	$200^{(6)}$	
	FT_lu, FT_u and PC3 IO	$V_{IN} \leq \text{Max}(V_{DDXXX})^{(4)}$	-	-	$\pm 150$	
		$\text{Max}(V_{DDXXX}) \leq V_{IN} \leq \text{Max}(V_{DDXXX}) + 1 \text{ V}^{(4)}$	-	-	$2500^{(3)(7)}$	
		$\text{Max}(V_{DDXXX}) + 1 \text{ V} < V_{IN} \leq 5.5 \text{ V}^{(4)(5)(7)}$	-	-	$250^{(7)}$	
	TT_xx input leakage current	$V_{IN} \leq \text{Max}(V_{DDXXX})^{(6)}$	-	-	$\pm 150$	
		$\text{Max}(V_{DDXXX}) \leq V_{IN} < 3.6 \text{ V}^{(6)}$	-	-	$2000^{(3)}$	
	OPAMPx_VINM (x=1,2) dedicated input leakage current (UFBGA132 only)	$T_J = 75^\circ\text{C}$	-	-	1	
$R_{PU}$	Weak pull-up equivalent resistor <sup>(8)</sup>	$V_{IN} = V_{SS}$	25	40	55	k $\Omega$
$R_{PD}$	Weak pull-down equivalent resistor <sup>(8)</sup>	$V_{IN} = V_{DDIOx}$	25	40	55	k $\Omega$
$C_{IO}$	I/O pin capacitance	-	-	5	-	pF

1. Refer to [Figure 22: I/O input characteristics](#).
2. Tested in production.
3. Guaranteed by design.
4.  $\text{Max}(V_{DDXXX})$  is the maximum value of all the I/O supplies. Refer to *Table: Legend/Abbreviations used in the pinout table*.
5. All TX\_xx IO except FT\_lu, FT\_u and PC3.
6. This value represents the pad leakage of the IO itself. The total product pad leakage is provided by this formula:  
 $I_{\text{Total\_leak\_max}} = 10 \mu\text{A} + [\text{number of IOs where } V_{IN} \text{ is applied on the pad}] \times I_{lkg}(\text{Max})$ .
7. To sustain a voltage higher than  $\text{MIN}(V_{DD}, V_{DDA}, V_{DDIO2}, V_{DDUSB}, V_{LCD}) + 0.3 \text{ V}$ , the internal Pull-up and Pull-Down resistors must be disabled.
8. Pull-up and pull-down resistors are designed with a true resistance in series with a switchable PMOS/NMOS. This PMOS/NMOS contribution to the series resistance is minimal (~10% order).

Figure 23. I/O AC characteristics definition<sup>(1)</sup>

1. Refer to [Table 60: I/O AC characteristics](#).

### 6.3.15 NRST pin characteristics

The NRST pin input driver uses the CMOS technology. It is connected to a permanent pull-up resistor,  $R_{PU}$ .

Unless otherwise specified, the parameters given in the table below are derived from tests performed under the ambient temperature and supply voltage conditions summarized in [Table 22: General operating conditions](#).

Table 61. NRST pin characteristics<sup>(1)</sup>

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{IL(NRST)}$	NRST input low level voltage	-	-	-	$0.3 \times V_{DDIOx}$	V
$V_{IH(NRST)}$	NRST input high level voltage	-	$0.7 \times V_{DDIOx}$	-	-	
$V_{hys(NRST)}$	NRST Schmitt trigger voltage hysteresis	-	-	200	-	mV
$R_{PU}$	Weak pull-up equivalent resistor <sup>(2)</sup>	$V_{IN} = V_{SS}$	25	40	55	k $\Omega$
$V_{F(NRST)}$	NRST input filtered pulse	-	-	-	70	ns
$V_{NF(NRST)}$	NRST input not filtered pulse	$1.71 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$	350	-	-	ns

1. Guaranteed by design.

2. The pull-up is designed with a true resistance in series with a switchable PMOS. This PMOS contribution to the series resistance is minimal (~10% order).

Table 66. ADC accuracy - limited test conditions 2<sup>(1)</sup>(2)(3) (continued)

Sym- bol	Parameter	Conditions <sup>(4)</sup>			Min	Typ	Max	Unit
THD	Total harmonic distortion	ADC clock frequency $\leq$ 80 MHz, Sampling rate $\leq$ 5.33 Msps, $2\text{ V} \leq V_{DDA}$	Single ended	Fast channel (max speed)	-	-74	-65	dB
				Slow channel (max speed)	-	-74	-67	
			Differential	Fast channel (max speed)	-	-79	-70	
				Slow channel (max speed)	-	-79	-71	

1. Guaranteed by design.
2. ADC DC accuracy values are measured after internal calibration.
3. ADC accuracy vs. negative Injection Current: Injecting negative current on any analog input pins should be avoided as this significantly reduces the accuracy of the conversion being performed on another analog input. It is recommended to add a Schottky diode (pin to ground) to analog pins which may potentially inject negative current.
4. The I/O analog switch voltage booster is enable when  $V_{DDA} < 2.4\text{ V}$  (BOOSTEN = 1 in the SYSCFG\_CFGR1 when  $V_{DDA} < 2.4\text{ V}$ ). It is disable when  $V_{DDA} \geq 2.4\text{ V}$ . No oversampling.

### 6.3.22 Temperature sensor characteristics

Table 74. TS characteristics

Symbol	Parameter	Min	Typ	Max	Unit
$T_L^{(1)}$	$V_{TS}$ linearity with temperature	-	$\pm 1$	$\pm 2$	$^{\circ}\text{C}$
Avg_Slope <sup>(2)</sup>	Average slope	2.3	2.5	2.7	mV/ $^{\circ}\text{C}$
$V_{30}$	Voltage at 30 $^{\circ}\text{C}$ ( $\pm 5^{\circ}\text{C}$ ) <sup>(3)</sup>	0.742	0.76	0.785	V
$t_{\text{START}}^{(1)}$ (TS_BUF) <sup>(1)</sup>	Sensor Buffer Start-up time in continuous mode <sup>(4)</sup>	-	8	15	$\mu\text{s}$
$t_{\text{START}}^{(1)}$	Start-up time when entering in continuous mode <sup>(4)</sup>	-	70	120	$\mu\text{s}$
$t_{\text{S\_temp}}^{(1)}$	ADC sampling time when reading the temperature	5	-	-	$\mu\text{s}$
$I_{\text{DD}}(\text{TS})^{(1)}$	Temperature sensor consumption from $V_{\text{DD}}$ , when selected by ADC	-	4.7	7	$\mu\text{A}$

1. Guaranteed by design.
2. Guaranteed by characterization results.
3. Measured at  $V_{\text{DDA}} = 3.0 \text{ V} \pm 10 \text{ mV}$ . The  $V_{30}$  ADC conversion result is stored in the TS\_CAL1 byte. Refer to [Table 8: Temperature sensor calibration values](#).
4. Continuous mode means Run/Sleep modes, or temperature sensor enable in Low-power run/Low-power sleep modes.

### 6.3.23 $V_{\text{BAT}}$ monitoring characteristics

Table 75.  $V_{\text{BAT}}$  monitoring characteristics

Symbol	Parameter	Min	Typ	Max	Unit
R	Resistor bridge for $V_{\text{BAT}}$	-	39	-	k $\Omega$
Q	Ratio on $V_{\text{BAT}}$ measurement	-	3	-	-
$E_r^{(1)}$	Error on Q	-10	-	10	%
$t_{\text{S\_vbat}}^{(1)}$	ADC sampling time when reading the VBAT	12	-	-	$\mu\text{s}$

1. Guaranteed by design.

Table 76.  $V_{\text{BAT}}$  charging characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{\text{BC}}$	Battery charging resistor	VBRS = 0	-	5	-	k $\Omega$
		VBRS = 1	-	1.5	-	

**SPI characteristics**

Unless otherwise specified, the parameters given in [Table 83](#) for SPI are derived from tests performed under the ambient temperature,  $f_{PCLKx}$  frequency and supply voltage conditions summarized in [Table 22: General operating conditions](#).

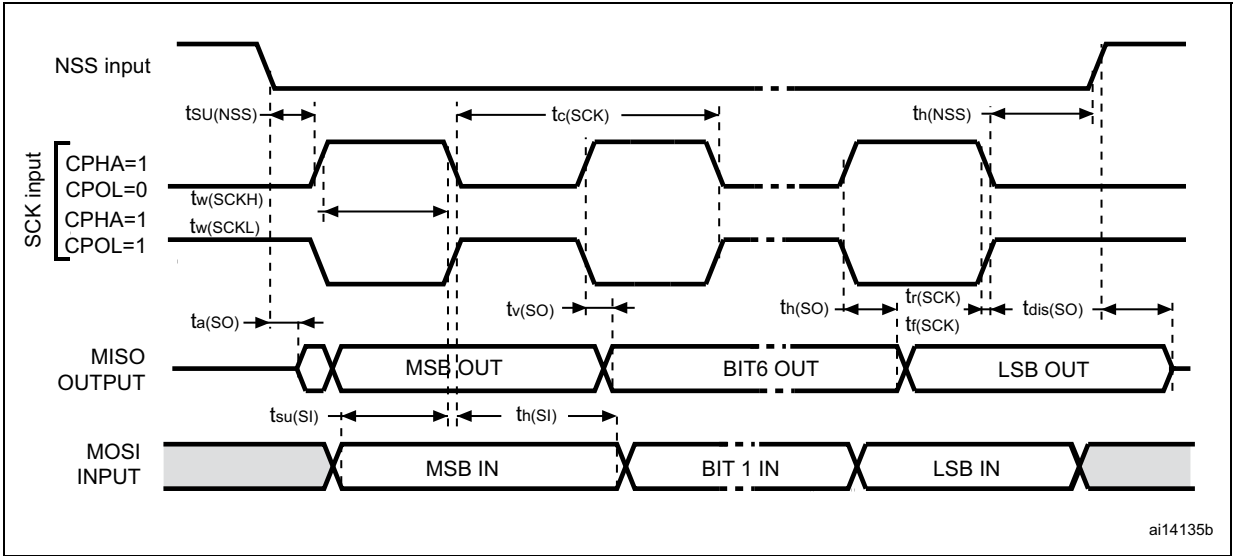
- Output speed is set to  $OSPEEDRy[1:0] = 11$
- Capacitive load  $C = 30$  pF
- Measurement points are done at CMOS levels:  $0.5 \times V_{DD}$

Refer to [Section 6.3.14: I/O port characteristics](#) for more details on the input/output alternate function characteristics (NSS, SCK, MOSI, MISO for SPI).

**Table 83. SPI characteristics<sup>(1)</sup>**

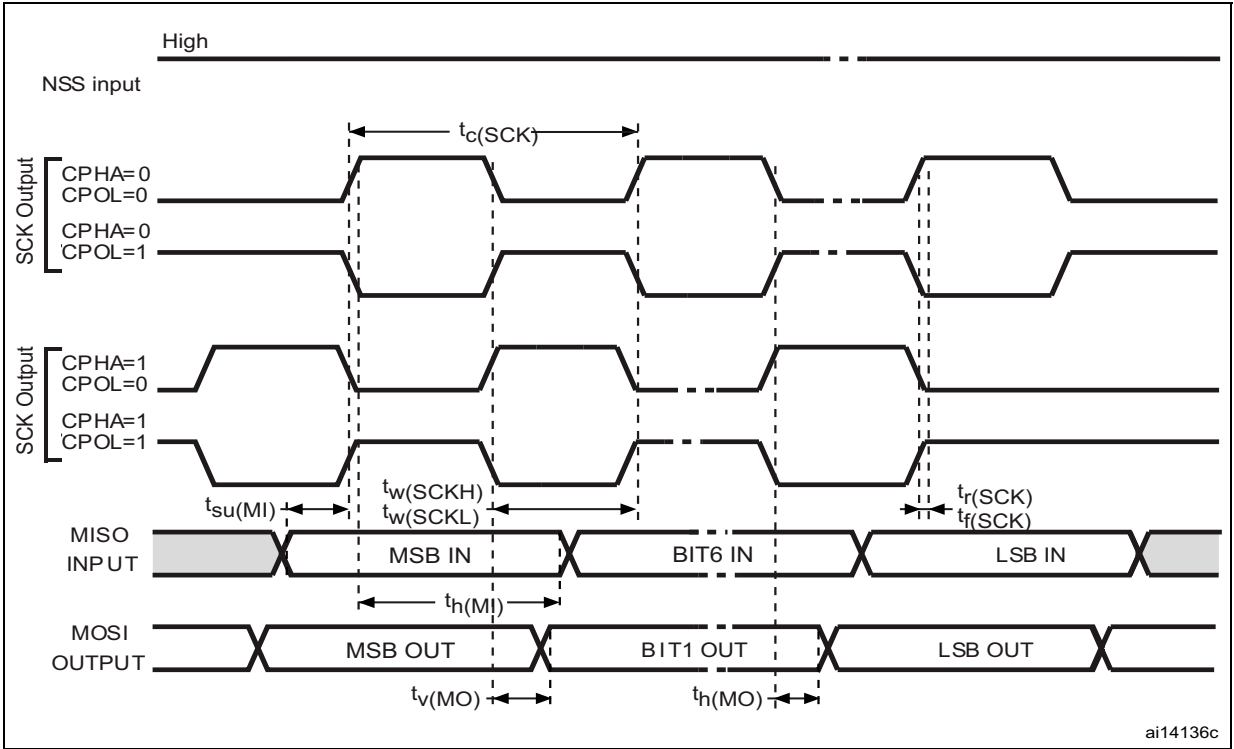
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$f_{SCK}$ $1/t_{c(SCK)}$	SPI clock frequency	Master mode receiver/full duplex $2.7 < V_{DD} < 3.6$ V Voltage Range 1	-	-	24	MHz
		Master mode receiver/full duplex $1.71 < V_{DD} < 3.6$ V Voltage Range 1			13	
		Master mode transmitter $1.71 < V_{DD} < 3.6$ V Voltage Range 1			40	
		Slave mode receiver $1.71 < V_{DD} < 3.6$ V Voltage Range 1			40	
		Slave mode transmitter/full duplex $2.7 < V_{DD} < 3.6$ V Voltage Range 1			26 <sup>(2)</sup>	
		Slave mode transmitter/full duplex $1.71 < V_{DD} < 3.6$ V Voltage Range 1			16 <sup>(2)</sup>	
		Voltage Range 2			13	
		$1.08 < V_{DDIO2} < 1.32$ V <sup>(3)</sup>			8	
$t_{su(NSS)}$	NSS setup time	Slave mode, SPI prescaler = 2	$4 \times T_{PCLK}$	-	-	ns
$t_{h(NSS)}$	NSS hold time	Slave mode, SPI prescaler = 2	$2 \times T_{PCLK}$	-	-	ns
$t_{w(SCKH)}$ $t_{w(SCKL)}$	SCK high and low time	Master mode	$T_{PCLK} - 2$	$T_{PCLK}$	$T_{PCLK} + 2$	ns
$t_{su(MI)}$	Data input setup time	Master mode	3.5	-	-	ns
$t_{su(SI)}$		Slave mode	3	-	-	
$t_{h(MI)}$	Data input hold time	Master mode	6.5	-	-	ns
$t_{h(SI)}$		Slave mode	3	-	-	
$t_{a(SO)}$	Data output access time	Slave mode	9	-	36	ns
$t_{dis(SO)}$	Data output disable time	Slave mode	9	-	16	ns

Figure 29. SPI timing diagram - slave mode and CPHA = 1



1. Measurement points are done at CMOS levels: 0.3  $V_{DD}$  and 0.7  $V_{DD}$ .

Figure 30. SPI timing diagram - master mode



1. Measurement points are done at CMOS levels: 0.3  $V_{DD}$  and 0.7  $V_{DD}$ .

### Quad SPI characteristics

Unless otherwise specified, the parameters given in [Table 84](#) and [Table 85](#) for Quad SPI are derived from tests performed under the ambient temperature,  $f_{\text{AHB}}$  frequency and  $V_{\text{DD}}$  supply voltage conditions summarized in [Table 22: General operating conditions](#), with the following configuration:

- Output speed is set to  $\text{OSPEEDRy}[1:0] = 11$
- Capacitive load  $C = 15$  or  $20$  pF
- Measurement points are done at CMOS levels:  $0.5 \times V_{\text{DD}}$

Refer to [Section 6.3.14: I/O port characteristics](#) for more details on the input/output alternate function characteristics.

**Table 84. Quad SPI characteristics in SDR mode<sup>(1)</sup>**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$F_{\text{CK}}$ $1/t_{\text{CK}}$	Quad SPI clock frequency	$1.71 < V_{\text{DD}} < 3.6 \text{ V}$ , $C_{\text{LOAD}} = 20 \text{ pF}$ Voltage Range 1	-	-	40	MHz
		$1.71 < V_{\text{DD}} < 3.6 \text{ V}$ , $C_{\text{LOAD}} = 15 \text{ pF}$ Voltage Range 1	-	-	48	
		$2.7 < V_{\text{DD}} < 3.6 \text{ V}$ , $C_{\text{LOAD}} = 15 \text{ pF}$ Voltage Range 1	-	-	60	
		$1.71 < V_{\text{DD}} < 3.6 \text{ V}$ , $C_{\text{LOAD}} = 20 \text{ pF}$ Voltage Range 2	-	-	26	
$t_{\text{w(CKH)}}$	Quad SPI clock high and low time	$f_{\text{AHBCLK}} = 48 \text{ MHz}$ , $\text{presc} = 0$	$t_{\text{CK}}/2 - 2$	-	$t_{\text{CK}}/2$	ns
$t_{\text{w(CKL)}}$			$t_{\text{CK}}/2$	-	$t_{\text{CK}}/2 + 2$	
$t_{\text{s(IN)}}$	Data input setup time	Voltage Range 1	4	-	-	
		Voltage Range 2	3.5	-	-	
$t_{\text{h(IN)}}$	Data input hold time	Voltage Range 1	5.5	-	-	
		Voltage Range 2	6.5	-	-	
$t_{\text{v(OUT)}}$	Data output valid time	Voltage Range 1	-	2.5	5	
		Voltage Range 2	-	3	5	
$t_{\text{h(OUT)}}$	Data output hold time	Voltage Range 1	1.5	-	-	
		Voltage Range 2	2	-	-	

1. Guaranteed by characterization results.

### 6.3.28 FSMC characteristics

Unless otherwise specified, the parameters given in [Table 90](#) to [Table 103](#) for the FMC interface are derived from tests performed under the ambient temperature,  $f_{\text{HCLK}}$  frequency and  $V_{\text{DD}}$  supply voltage conditions summarized in [Table 22](#), with the following configuration:

- Output speed is set to  $\text{OSPEEDRy}[1:0] = 11$
- Capacitive load  $C = 30 \text{ pF}$
- Measurement points are done at CMOS levels:  $0.5V_{\text{DD}}$

Refer to [Section 6.3.14: I/O port characteristics](#) for more details on the input/output characteristics.

#### Asynchronous waveforms and timings

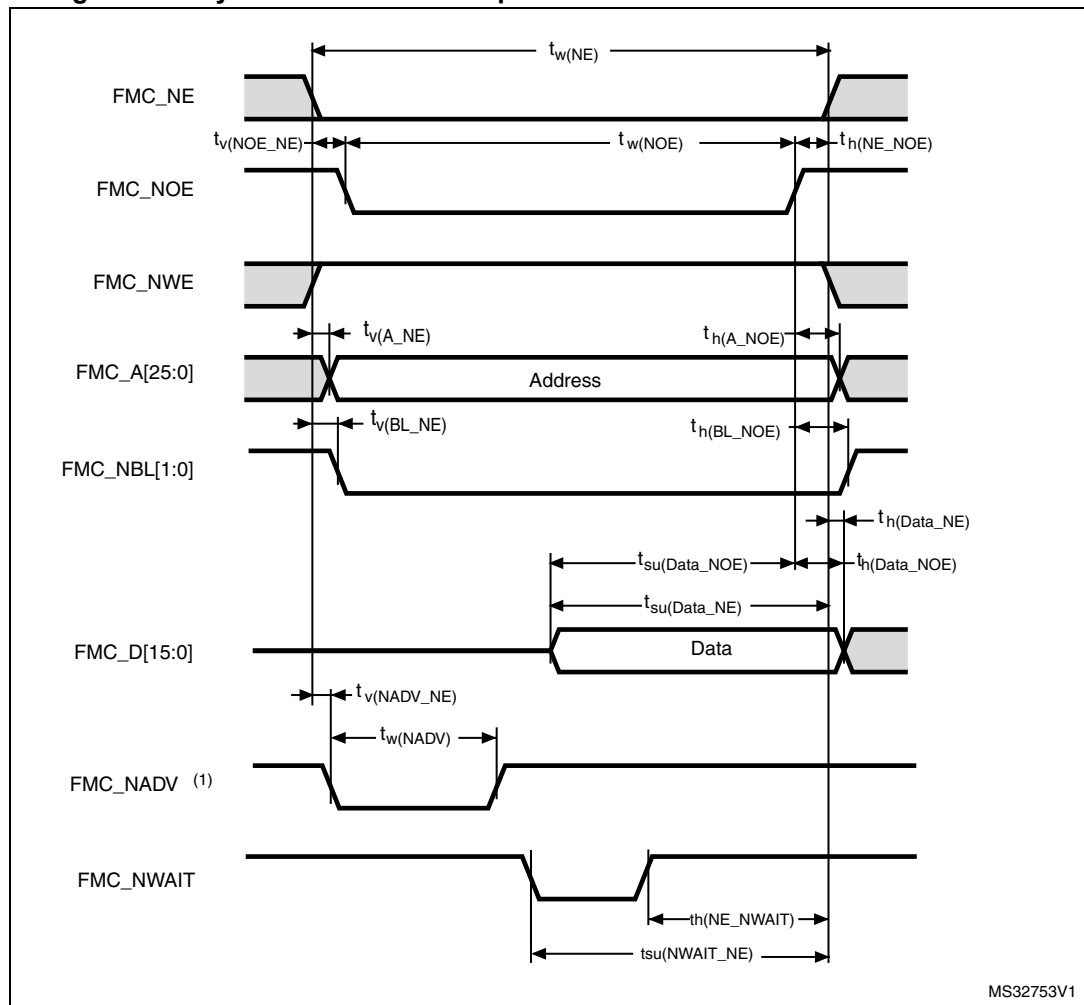
[Figure 37](#) through [Figure 40](#) represent asynchronous waveforms and [Table 90](#) through [Table 97](#) provide the corresponding timings. The results shown in these tables are obtained with the following FMC configuration:

- $\text{AddressSetupTime} = 0x1$
- $\text{AddressHoldTime} = 0x1$
- $\text{DataSetupTime} = 0x1$  (except for asynchronous NWAIT mode,  $\text{DataSetupTime} = 0x5$ )
- $\text{BusTurnAroundDuration} = 0x0$

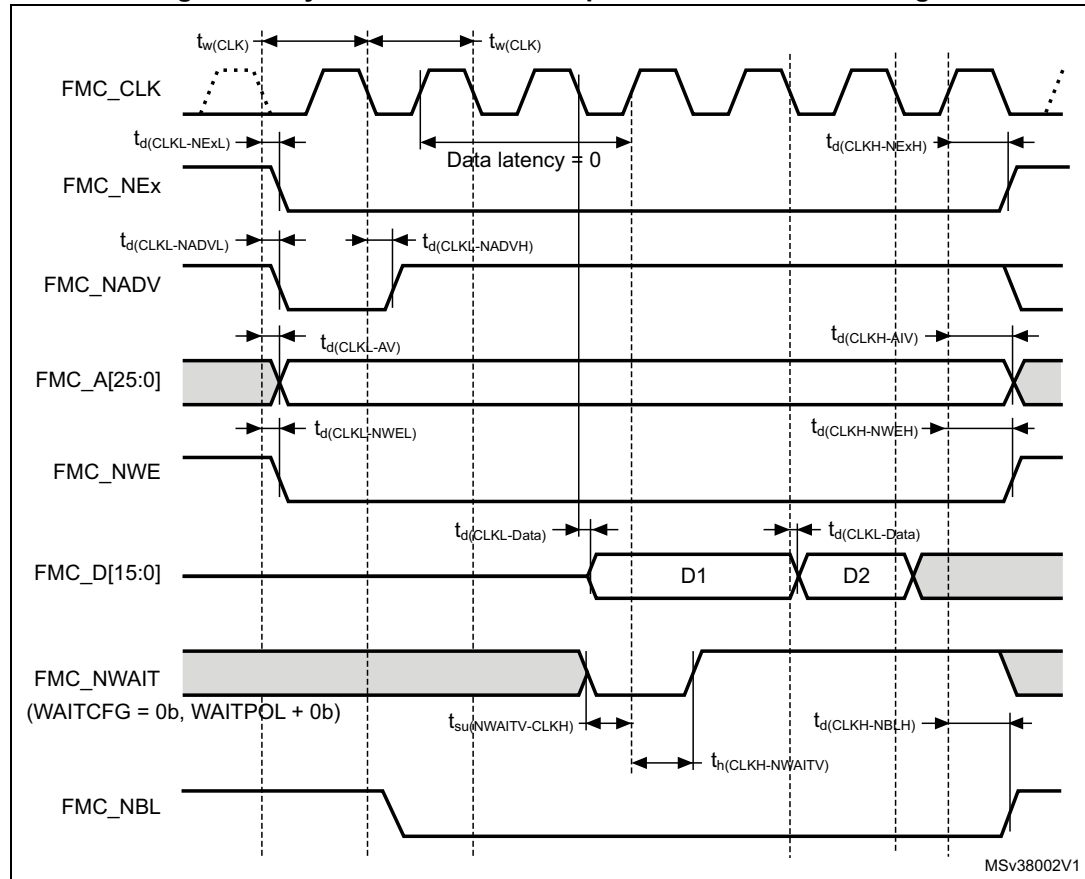
In all timing tables, the THCLK is the HCLK clock period.



Figure 37. Asynchronous non-multiplexed SRAM/PSRAM/NOR read waveforms



1. CL = 30 pF.
2. Guaranteed by characterization results.

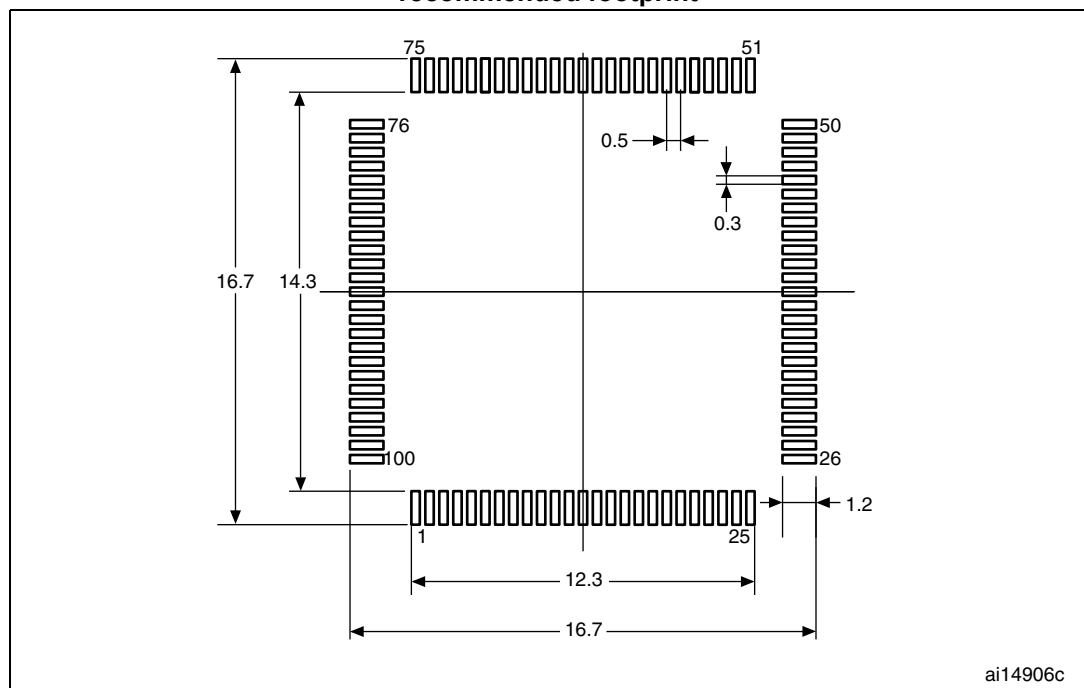
**Figure 44. Synchronous non-multiplexed PSRAM write timings**

**Table 107. LQPF100 - 100-pin, 14 x 14 mm low-profile quad flat package mechanical data (continued)**

Symbol	millimeters			inches <sup>(1)</sup>		
	Min	Typ	Max	Min	Typ	Max
D3	-	12.000	-	-	0.4724	-
E	15.800	16.000	16.200	0.6220	0.6299	0.6378
E1	13.800	14.000	14.200	0.5433	0.5512	0.5591
E3	-	12.000	-	-	0.4724	-
e	-	0.500	-	-	0.0197	-
L	0.450	0.600	0.750	0.0177	0.0236	0.0295
L1	-	1.000	-	-	0.0394	-
k	0.0°	3.5°	7.0°	0.0°	3.5°	7.0°
ccc	-	-	0.080	-	-	0.0031

1. Values in inches are converted from mm and rounded to 4 decimal digits.

**Figure 56. LQFP100 - 100-pin, 14 x 14 mm low-profile quad flat recommended footprint**



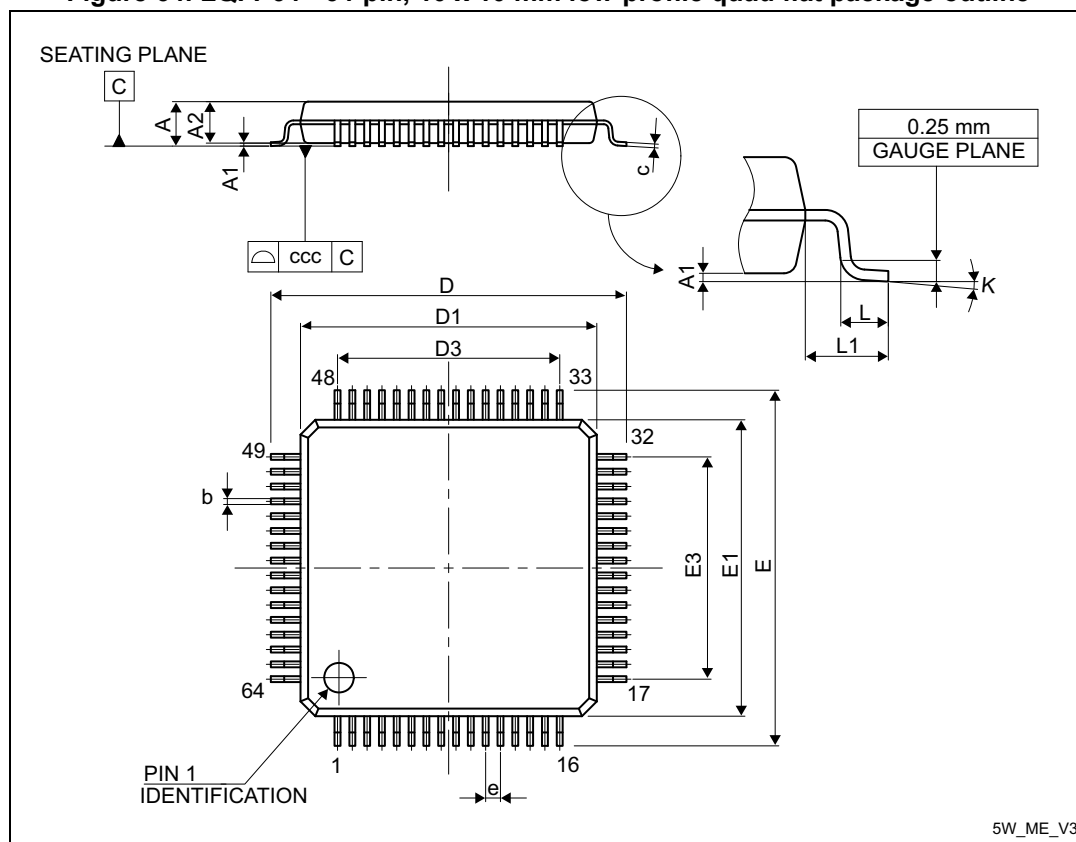
1. Dimensions are expressed in millimeters.

### Device marking

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

## 7.6 LQFP64 package information

Figure 64. LQFP64 - 64-pin, 10 x 10 mm low-profile quad flat package outline



1. Drawing is not to scale.

Table 112. LQFP64 - 64-pin, 10 x 10 mm low-profile quad flat package mechanical data

Symbol	millimeters			inches <sup>(1)</sup>		
	Min	Typ	Max	Min	Typ	Max
A	-	-	1.600	-	-	0.0630
A1	0.050	-	0.150	0.0020	-	0.0059
A2	1.350	1.400	1.450	0.0531	0.0551	0.0571
b	0.170	0.220	0.270	0.0067	0.0087	0.0106
c	0.090	-	0.200	0.0035	-	0.0079
D	-	12.000	-	-	0.4724	-
D1	-	10.000	-	-	0.3937	-
D3	-	7.500	-	-	0.2953	-
E	-	12.000	-	-	0.4724	-
E1	-	10.000	-	-	0.3937	-

Using the values obtained in [Table 113](#)  $T_{Jmax}$  is calculated as follows:

– For LQFP64, 45 °C/W

$$T_{Jmax} = 100\text{ °C} + (45\text{ °C/W} \times 134\text{ mW}) = 100\text{ °C} + 6.03\text{ °C} = 106.03\text{ °C}$$

This is above the range of the suffix 6 version parts ( $-40 < T_J < 105\text{ °C}$ ).

In this case, parts must be ordered at least with the temperature range suffix 7 (see [Section 8: Part numbering](#)) unless we reduce the power dissipation in order to be able to use suffix 6 parts.

Refer to [Figure 67](#) to select the required temperature range (suffix 6 or 7) according to your ambient temperature or power requirements.

**Figure 67. LQFP64  $P_D$  max vs.  $T_A$**

